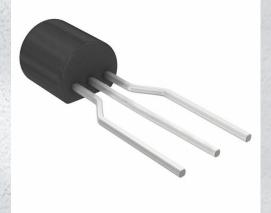


MPSA92RL1G Datasheet

www.digi-electronics.com



DiGi Electronics Part Number	MPSA92RL1G-DG
Manufacturer	onsemi
Manufacturer Product Number	MPSA92RL1G
Description	TRANS PNP 300V 0.5A TO92
Detailed Description	Bipolar (BJT) Transistor PNP 300 V 500 mA 50MHz 6 25 mW Through Hole TO-92 (TO-226)

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Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
MPSA92RL1G	onsemi
Series:	Product Status:
-	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
PNP	500 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
300 V	500mV @ 2mA, 20mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:
250nA (ICBO)	25 @ 30mA, 10V
Power - Max:	Frequency - Transition:
625 mW	50MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Package / Case:	Supplier Device Package:
TO-226-3, TO-92-3 Long Body (Formed Leads)	TO-92 (TO-226)
Base Product Number:	
MPSA92	

Environmental & Export classification

Moisture Sensitivity Level (MSL):	REACH Status:
1 (Unlimited)	REACH Unaffected
ECCN:	HTSUS:
EAR99	8541.21.0095

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High Voltage Transistors

PNP Silicon

Features

• Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
	IPSA93 IPSA92	V _{CEO}	-200 -300	Vdc
	IPSA93 IPSA92	V _{CBO}	-200 -300	Vdc
Emitter – Base Voltage		V_{EBO}	-5.0	Vdc
Collector Current – Continuous	3	Ι _C	-500	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C		P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C		PD	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	n	T _J , T _{stg}	−55 to +150	°C

THERMAL CHARACTERISTICS

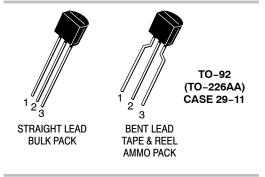
Characteristic	Symbol	Мах	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

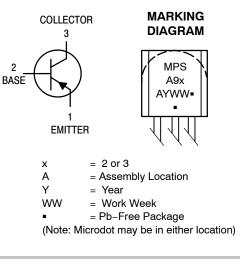
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS			•	•	•
Collector – Emitter Breakdown Voltage (Note 1) $(I_C = -1.0 \text{ mAdc}, I_B = 0)$	MPSA92 MPSA93	V _{(BR)CEO}	-300 -200		Vdc
Collector – Base Breakdown Voltage $(I_C = -100 \ \mu Adc, I_E = 0)$	MPSA92 MPSA93	V _{(BR)CBO}	-300 -200		Vdc
Emitter – Base Breakdown Voltage ($I_E = -100 \ \mu Adc, I_C = 0$)		V _{(BR)EBO}	-5.0	-	Vdc
Collector Cutoff Current ($V_{CB} = -200$ Vdc, $I_E = 0$) ($V_{CB} = -160$ Vdc, $I_E = 0$)	MPSA92 MPSA93	I _{CBO}		-0.25 -0.25	μAdc
Emitter Cutoff Current ($V_{EB} = -3.0 \text{ Vdc}, I_C = 0$)		I _{EBO}	-	-0.1	μAdc
ON CHARACTERISTICS (Note 1)					
DC Current Gain ($I_C = -1.0 \text{ mAdc}$, $V_{CE} = -10 \text{ Vdc}$) ($I_C = -10 \text{ mAdc}$, $V_{CE} = -10 \text{ Vdc}$)	All Types All Types	h _{FE}	25 40		_
(I _C = -30 mAdc, V _{CE} = -10 Vdc)	MPSA92 MPSA93		25 25	-	
Collector – Emitter Saturation Voltage ($I_C = -20$ mAdc, $I_B = -2.0$ mAdc)	MPSA92 MPSA93	V _{CE(sat)}		-0.5 -0.4	Vdc
Base–Emitter Saturation Voltage ($I_C = -20 \text{ mAdc}, I_B = -2.0 \text{ mAdc}$)		V _{BE(sat)}	-	-0.9	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain – Bandwidth Product (I _C = –10 mAdc, V _{CE} = –20 Vdc, f = 100 MHz)		f _T	50	-	MHz
Collector-Base Capacitance $(V_{CB} = -20 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$	MPSA92 MPSA93	C _{cb}		6.0 8.0	pF

1. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2%.

ORDERING INFORMATION

Device	Package	Shipping [†]
MPSA92G	TO-92 (Pb-Free)	5000 Units / Box
MPSA92RL1G	TO-92 (Pb-Free)	2000 / Tape & Reel
MPSA92RLRA	TO-92	2000 / Tape & Reel
MPSA92RLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel
MPSA92RLRMG	TO-92 (Pb-Free)	2000 / Ammo Pack
MPSA92RLRPG	TO-92 (Pb-Free)	2000 / Ammo Pack
MPSA92ZL1G	TO-92 (Pb-Free)	2000 / Ammo Pack
MPSA93G	TO-92 (Pb-Free)	5000 Units / Box
MPSA93RLRMG	TO-92 (Pb-Free)	2000 / Ammo Pack

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

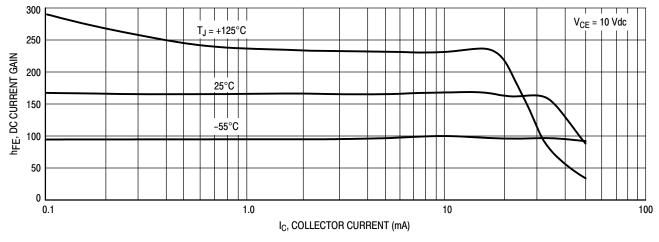
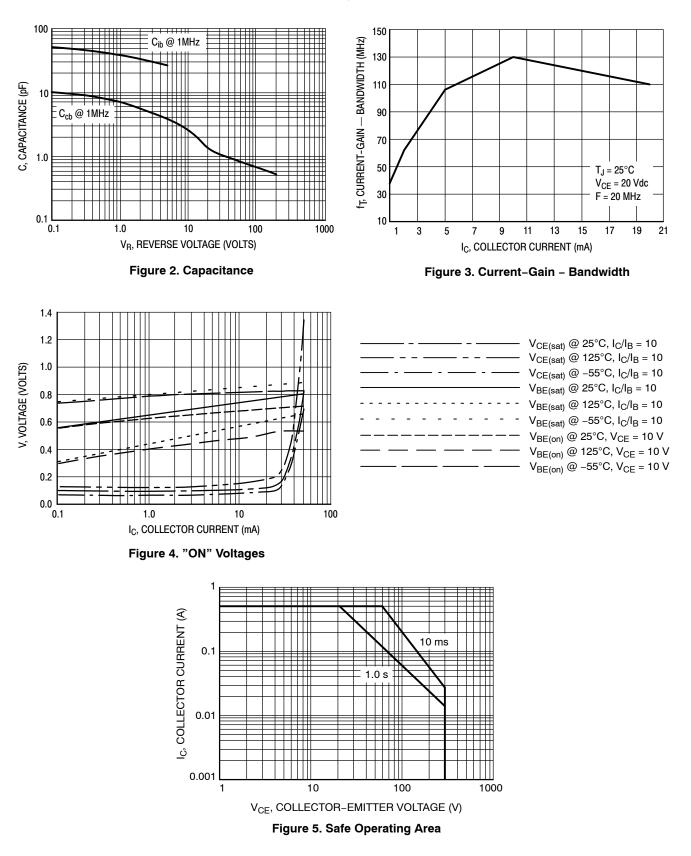


Figure 1. DC Current Gain

MPSA92, MPSA93

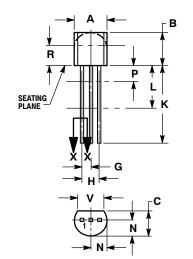


PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 029-11 **ISSUE AM**

STRAIGHT LEAD

BULK PACK



R

Τ SEATING Ρ

B



SECTION X-X

BENT LEAD

TAPE & REEL

AMMO PACK

.1

SECTION X-X

NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH. CONTOUR OF PACKAGE BEYOND DIMENSION R 3.
- IS UNCONTROLLED. LEAD DIMENSION IS UNCONTROLLED IN P AND

 BEYOND DIMENSION K MINIMUM.					
	INCHES MILLIMETERS				
DIM	MIN	MAX	MIN	MAX	

	INTOTILO			LILIIO
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
۷	0.135		3.43	

STYLE 14: PIN 1. EMITTER 2.

COLLECTOR BASE 3.

NOTES

2.

- DIMENSIONING AND TOLERANCING PER 1.
- ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS.
- 3 CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED
- 4
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS		
DIM	MIN	MAX	
Α	4.45	5.20	
В	4.32	5.33	
С	3.18	4.19	
D	0.40	0.54	
G	2.40	2.80	
J	0.39	0.50	
Κ	12.70		
Ν	2.04	2.66	
Ρ	1.50	4.00	
R	2.93		
۷	3.43		

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